

To all our customers

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Renesas Technology Corp.  
Customer Support Dept.  
April 1, 2003

## Cautions

Keep safety first in your circuit designs!

1. Renesas Technology Corporation puts the maximum effort into making semiconductor products better and more reliable, but there is always the possibility that trouble may occur with them. Trouble with semiconductors may lead to personal injury, fire or property damage.

Remember to give due consideration to safety when making your circuit designs, with appropriate measures such as (i) placement of substitutive, auxiliary circuits, (ii) use of nonflammable material or (iii) prevention against any malfunction or mishap.

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# 2SC1515(K)

Silicon NPN Triple Diffused

**RENESAS**

ADE-208-1055 (Z)  
1st. Edition  
Mar. 2001

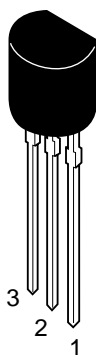
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## Application

High voltage switching

## Outline

TO-92 (1)



1. Emitter
2. Collector
3. Base

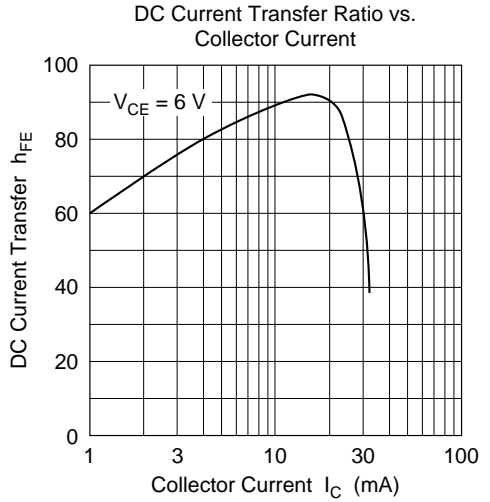
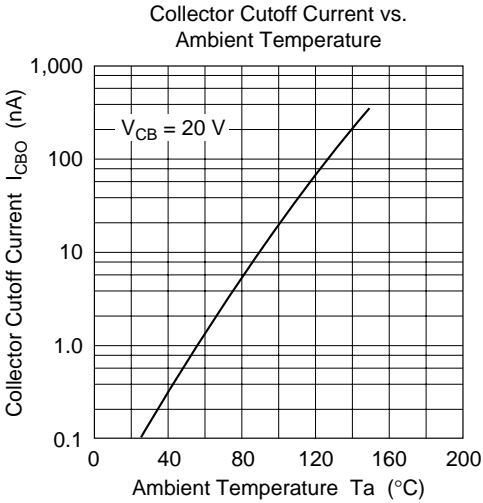
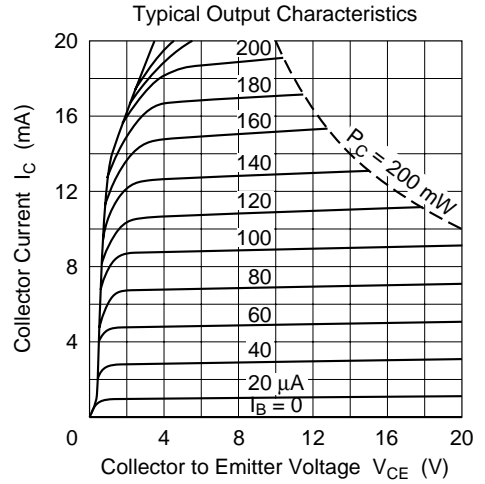
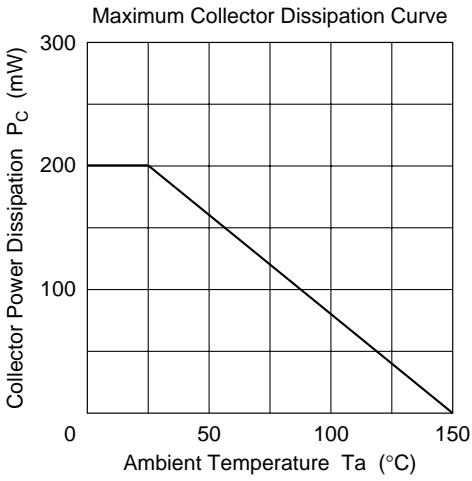
## 2SC1515 (K)

### Absolute Maximum Ratings (Ta = 25°C)

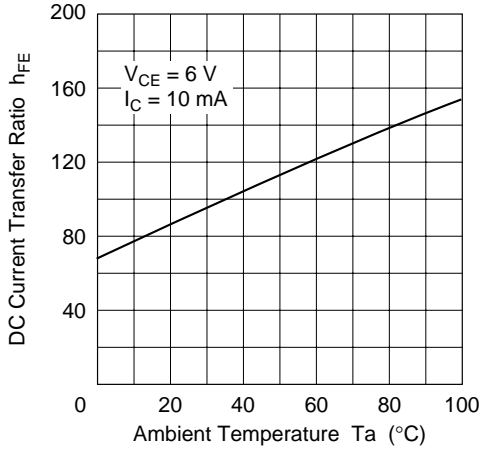
Item	Symbol	Ratings	Unit
Collector to base voltage	$V_{CBO}$	200	V
Collector to emitter voltage	$V_{CES}$	200	V
	$V_{CEO}$	150	V
Emitter to base voltage	$V_{EBO}$	5	V
Collector current	$I_C$	50	mA
Collector power dissipation	$P_C$	200	mW
Junction temperature	$T_j$	150	°C
Storage temperature	$T_{stg}$	-55 to +150	°C

### Electrical Characteristics (Ta = 25°C)

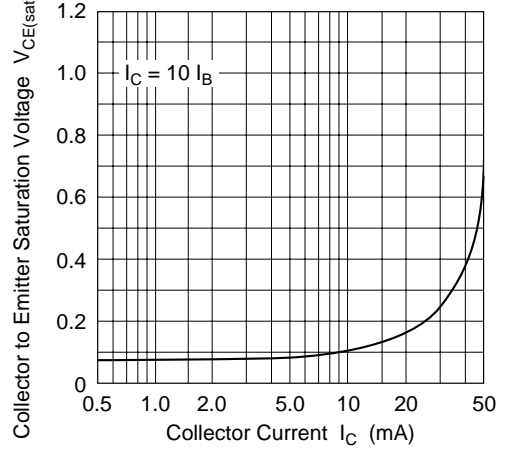
Item	Symbol	Min	Typ	Max	Unit	Test conditions
Collector to emitter breakdown voltage	$V_{(BR)CES}$	200	—	—	V	$I_C = 10 \mu A, R_{BE} = 0$
	$V_{(BR)CEO}$	150	—	—	V	$I_C = 1 \text{ mA}, R_{BE} =$
Emitter to base breakdown voltage	$V_{(BR)EBO}$	5	—	—	V	$I_E = 10 \mu A, I_C = 0$
Collector cutoff current	$I_{CBO}$	—	—	0.1	$\mu A$	$V_{CB} = 20 \text{ V}, I_E = 0$
DC current transfer ratio	$h_{FE}$	30	—	300		$V_{CE} = 6 \text{ V}, I_C = 10 \text{ mA}$
Collector to emitter saturation voltage	$V_{CE(sat)}$	—	—	1.0	V	$I_C = 10 \text{ mA}, I_B = 1 \text{ mA}$
Base to emitter saturation voltage	$V_{BE(sat)}$	—	—	1.5	V	$I_C = 10 \text{ mA}, I_B = 1 \text{ mA}$
Gain bandwidth product	$f_T$	60	—	—	MHz	$V_{CE} = 6 \text{ V}, I_C = 10 \text{ mA}$
Collector output capacitance	$C_{ob}$	—	—	10	pF	$V_{CB} = 6 \text{ V}, I_E = 0, f = 1 \text{ MHz}$



DC Current Transfer Ratio vs. Ambient Temperature

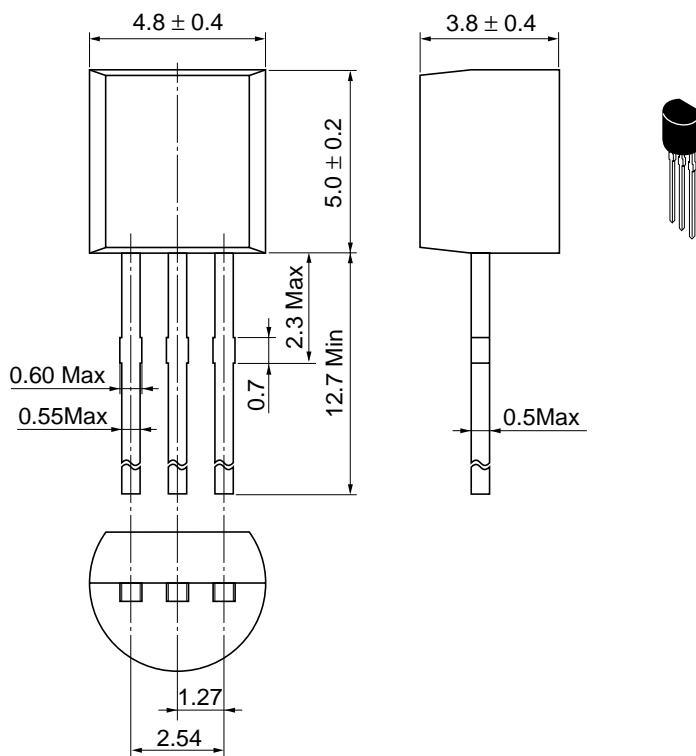


Collector to Emitter Saturation Voltage vs. Collector Current



Package Dimensions

As of January, 2001  
Unit: mm



Hitachi Code	TO-92 (1)
JEDEC	Conforms
EIAJ	Conforms
Mass (reference value)	0.25 g

## Cautions

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